

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE4005 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge. This device is suitable for use as a Battery protection or in other switching application.

General Features

V_{DS} =40V,I_D =5A

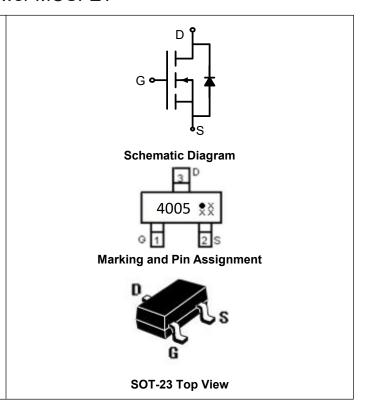
 $R_{DS(ON)} = 22m\Omega @ V_{GS}=10V(Typ)$

 $R_{DS(ON)} = 36m\Omega @ V_{GS} = 4.5V(Typ)$

- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- Battery switch
- ●DC/DC converter



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
4005 👯	NCE4005	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	40	V
Gate-Source Voltage	VGS	±20	V
Drain Current-Continuous	I _D	5	Α
Drain Current-Pulsed (Note 1)	I _{DM}	20	Α
Single pulse avalanche energy (Note 5)	Eas	42	mJ
Maximum Power Dissipation	PD	1	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance,Junction-to-Ambient (Note 2)	R _{0JA}	125	°C/W	
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Electrical Characteristics (T_A=25[°]Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA		-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.0	1.6	2.2	V
Dunin Course On State Besistance	Б	V _{GS} =10V, I _D =5A	_	22	26	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =3A	_	36	46	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =5A	-	9	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	Clss	\/ 00\/\/ 0\/	-	530	-	PF
Output Capacitance	Coss	V_{DS} =20V, V_{GS} =0V, F=1.0MHz	-	68	-	PF
Reverse Transfer Capacitance	Crss	F-1.UIVIDZ	-	58	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}	V _{DD} =20V,I _D =5A	-	10	-	nS
Turn-on Rise Time	t _r		-	8	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{GEN} =1 Ω	-	25	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg	\/ 00\/ FA	-	15.5	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=20V, I_{D}=5A,$	-	2.9	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	3.5	-	nC
Drain-Source Diode Characteristics	,					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =5A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		_	-	5	Α

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width $\leq 300 \mu s$, Duty Cycle $\leq 2\%$.
- **4.** Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=20V,VG=10V,L=0.5mH,Rg=25 Ω



Typical Electrical and Thermal Characteristics

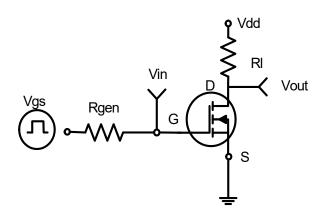


Figure 1:Switching Test Circuit

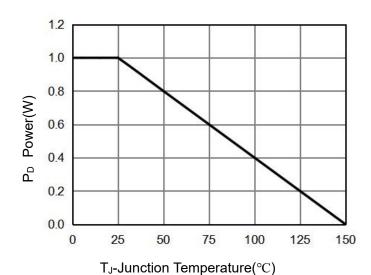


Figure 3 Power Dissipation

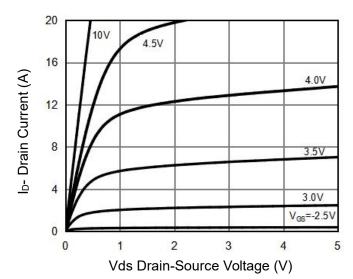


Figure 5 Output Characteristics

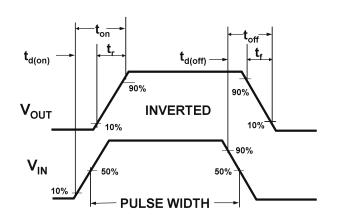


Figure 2:Switching Waveforms

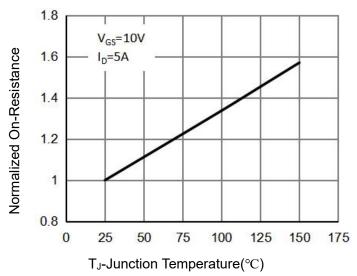


Figure 4 Drain-Source On-Resistance

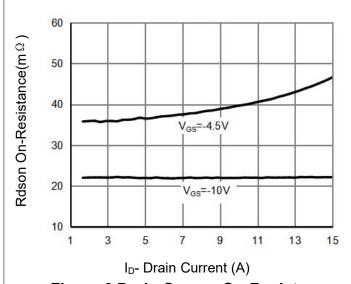


Figure 6 Drain-Source On-Resistance



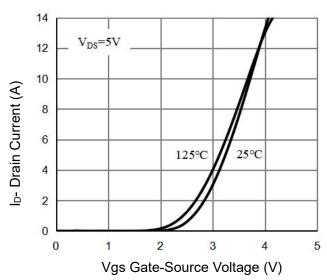
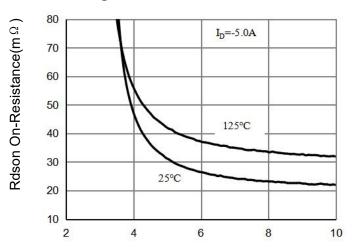
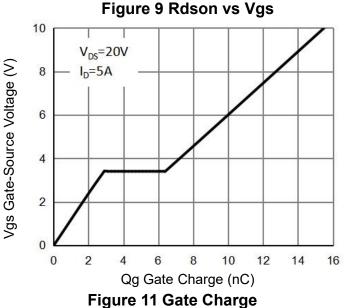


Figure 7 Transfer Characteristics



Vgs Gate-Source Voltage (V)



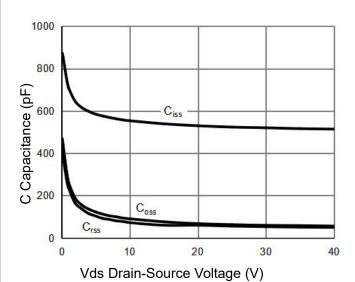
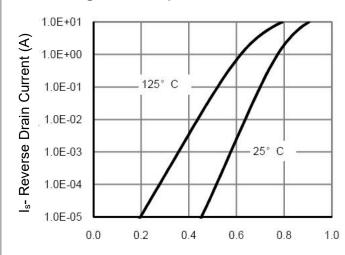


Figure 10 Capacitance vs Vds



Vsd Source-Drain Voltage (V)

Figure 11 Source- Drain Diode Forward

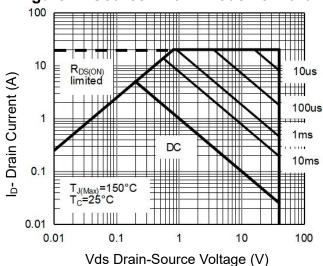


Figure 12 Safe Operation Area



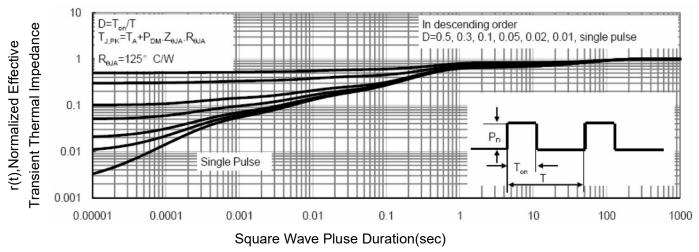
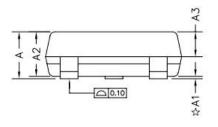
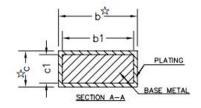


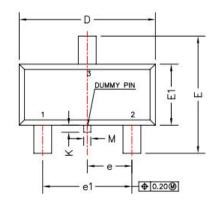
Figure 13 Normalized Maximum Transient Thermal Impedance

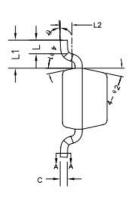


SOT-23 Package Information









Cumbal	Millimeters			
Symbol	Min.	Max.		
Α	0.89	1.12		
A1	0.01	0.10		
A2	0.88	1.02		
A3	0.43	0.63		
b	0.36	0.50		
b1	0.35	0.45		
С	0.14	0.20		
c1	0.14	0.16		
D	2.80	3.00		
E	2.35	2.64		
E1	1.20	1.40		
е	0.90	1.00		
e1	1.80	2.00		
L	0.40	0.60		
L1	0.6REF			
L2	0.25BSC			
M	0.10	0.25		
K	0.00	0.25		
θ	0°	8°		
θ1	10°	14°		
θ2	10°	14°		



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